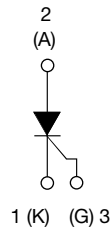
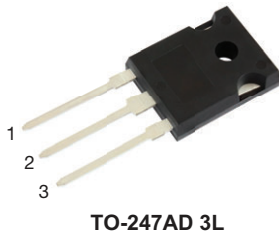


## Thyristor High Voltage, Phase Control SCR, 40 A



### FEATURES

- Low  $I_{GT}$  parts available
- Designed and qualified according to JEDEC® - JESD 47
- Flexible solution for reliable AC power rectification
- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

PRIMARY CHARACTERISTICS	
$I_{T(AV)}$	35 A
$V_{DRM}/V_{RRM}$	1200 V
$V_{TM}$	1.45 V
$I_{GT}$	150 mA
$T_J$	-40 °C to +125 °C
Package	TO-247AD 3L
Circuit configuration	Single SCR

### APPLICATIONS

- Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

### DESCRIPTION

The VS-40TPS12.. high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. AEC-Q101 qualified P/N available (VS-40TPS12LHM3, VS-40TPS12ALHM3).

MAJOR RATINGS AND CHARACTERISTICS			
PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$	Sinusoidal waveform	35	A
$I_{RMS}$		55	
$V_{RRM}/V_{DRM}$		1200	V
$I_{TSM}$		600	A
$V_T$	40 A, $T_J = 25\text{ °C}$	1.45	V
dv/dt		1000	V/ $\mu$ s
di/dt		100	A/ $\mu$ s
$T_J$		-40 to +125	°C

VOLTAGE RATINGS			
PART NUMBER	$V_{RRM}/V_{DRM}$ , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM}/I_{DRM}$ AT 125 °C mA
VS-40TPS12AL-M3	1200	1300	10
VS-40TPS12L-M3	1200	1300	



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current	$I_{T(AV)}$	$T_C = 79\text{ }^\circ\text{C}$ , 180° conduction half sine wave		35	A
Maximum continuous RMS on-state current as AC switch	$I_{T(RMS)}$			55	
Maximum peak, one-cycle non-repetitive surge current	$I_{TSM}$	10 ms sine pulse, rated $V_{RRM}$ applied		500	A <sup>2</sup> s
		10 ms sine pulse, no voltage reapplied		600	
Maximum $I^2t$ for fusing	$I^2t$	10 ms sine pulse, rated $V_{RRM}$ applied		1250	
		10 ms sine pulse, no voltage reapplied		1760	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to }10\text{ ms}$ , no voltage reapplied		17 600	A <sup>2</sup> √s
Low level value of threshold voltage	$V_{T(TO)1}$	$T_J = 125\text{ }^\circ\text{C}$		1.02	V
High level value of threshold voltage	$V_{T(TO)2}$			1.23	
Low level value of on-state slope resistance	$r_{t1}$			9.74	mΩ
High level value of on-state slope resistance	$r_{t2}$			7.50	
Maximum peak on-state voltage	$V_{TM}$	110 A, $T_J = 25\text{ }^\circ\text{C}$		1.85	V
Maximum rate of rise of turned-on current	$di/dt$	$T_J = 25\text{ }^\circ\text{C}$		100	A/μs
Maximum holding current	$I_H$	Anode supply = 6 V, resistive load, initial $T_J = 1\text{ A}$ , $I_T = 25\text{ }^\circ\text{C}$		300	mA
Maximum latching current	$I_L$	Anode supply = 6 V, resistive load, $T_J = 25\text{ }^\circ\text{C}$		350	
Maximum reverse and direct leakage current	$I_{RRM}/I_{DRM}$	$T_J = 25\text{ }^\circ\text{C}$	$V_R = \text{rated } V_{RRM}/V_{DRM}$	0.5	mA
		$T_J = 125\text{ }^\circ\text{C}$		10	
Maximum rate of rise of off-state voltage 40TPS12A	$dv/dt$	$T_J = T_J \text{ maximum, linear to } 80\% V_{DRM}$ , $R_g - k = 100\text{ }^\circ\Omega$		500	V/μs
Maximum rate of rise of off-state voltage 40TPS12				1000	

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	$P_{GM}$			10	W
Maximum average gate power	$P_{G(AV)}$			2.5	
Maximum peak gate current	$I_{GM}$			2.5	A
Maximum peak negative gate voltage	$-V_{GM}$			10	V
Maximum required DC gate voltage to trigger	$V_{GT}$	$T_J = -40\text{ }^\circ\text{C}$	Anode supply = 6 V resistive load	2.0	V
		$T_J = 25\text{ }^\circ\text{C}$		1.7	
		$T_J = 125\text{ }^\circ\text{C}$		1.3	
Maximum required DC gate current to trigger	$I_{GT}$	$T_J = -40\text{ }^\circ\text{C}$	Anode supply = 6 V resistive load	200	mA
		$T_J = 25\text{ }^\circ\text{C}$		150	
		$T_J = 125\text{ }^\circ\text{C}$		80	
		$T_J = 25\text{ }^\circ\text{C}$ , for 40TPS12A		40	
Maximum DC gate voltage not to trigger for 40TPS12	$V_{GD}$	$T_J = 125\text{ }^\circ\text{C}$ , $V_{DRM} = \text{rated value}$		0.25	V
Maximum DC gate current not to trigger for 40TPS12	$I_{GD}$			6	mA
Maximum DC gate voltage not to trigger for 40TPS12A	$V_{GD}$	$T_J = 125\text{ }^\circ\text{C}$ , $V_{DRM} = \text{rated value}$		0.15	V
Maximum DC gate current not to trigger for 40TPS12A	$I_{GD}$			1	mA



THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-40 to +125	°C
Maximum thermal resistance, junction to case	$R_{thJC}$	DC operation	0.6	°C/W
Maximum thermal resistance, junction to ambient	$R_{thJA}$		40	
Maximum thermal resistance, case to heat sink	$R_{thCS}$	Mounting surface, smooth and greased	0.25	
Approximate weight			6	g
			0.21	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-247AD 3L	40TPS12AL	
			40TPS12L	

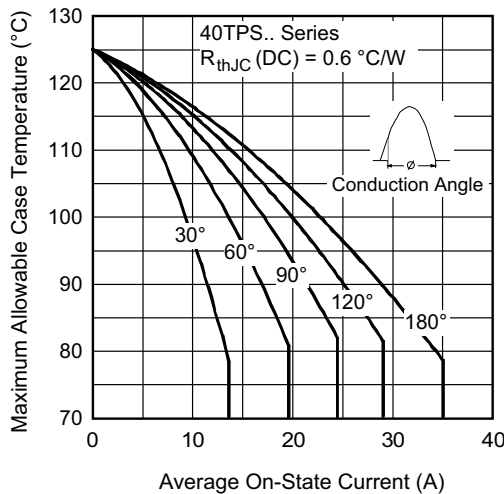


Fig. 1 - Current Rating Characteristics

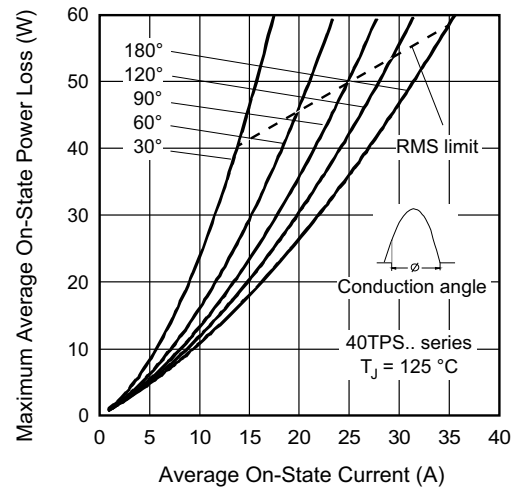


Fig. 3 - On-State Power Loss Characteristics

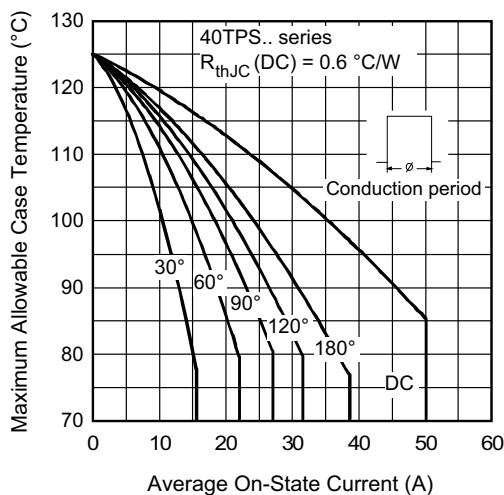


Fig. 2 - Current Rating Characteristics

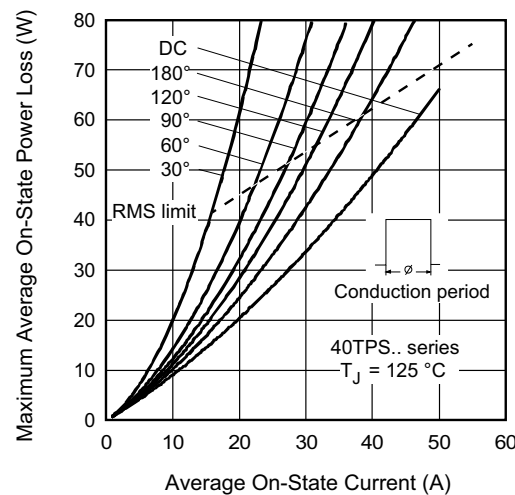


Fig. 4 - On-State Power Loss Characteristics

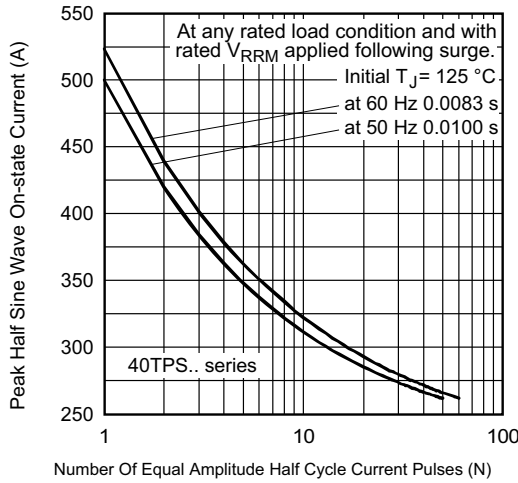


Fig. 5 - Maximum Non-Repetitive Surge Current

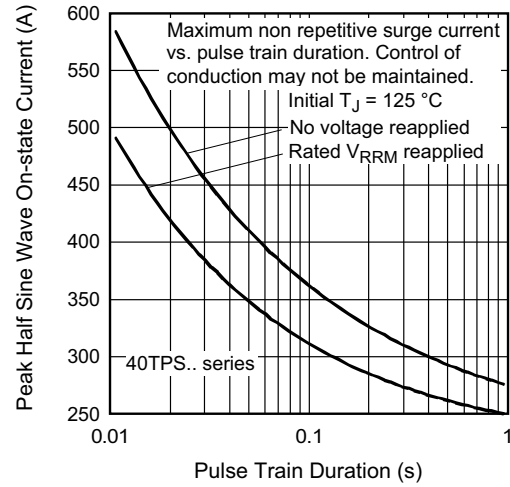


Fig. 6 - Maximum Non-Repetitive Surge Current

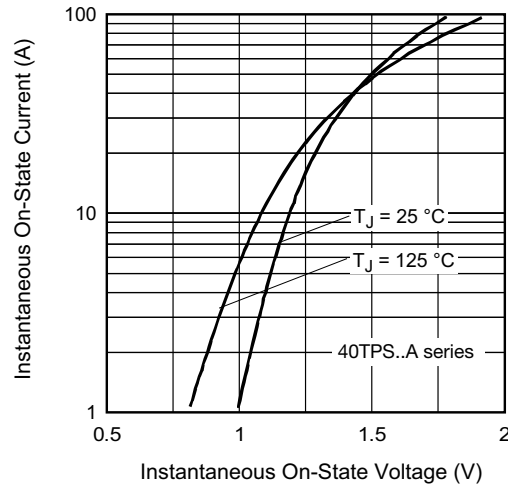


Fig. 7 - On-State Voltage Drop Characteristics

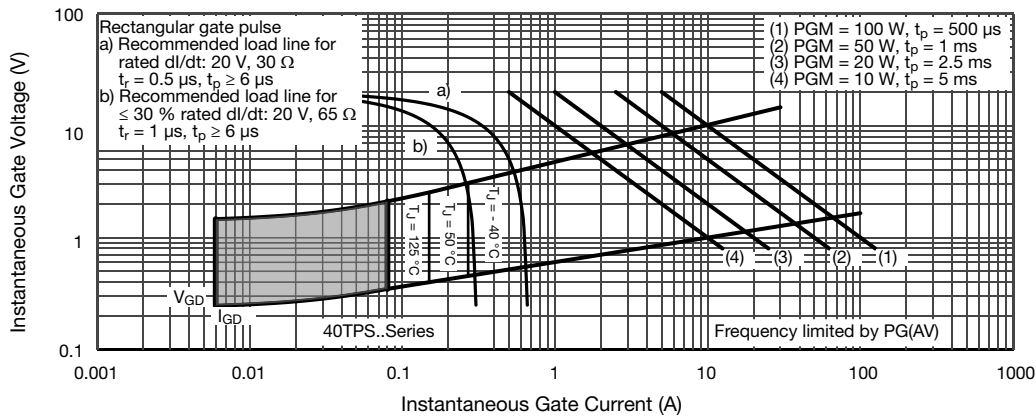


Fig. 8 - Gate Characteristics

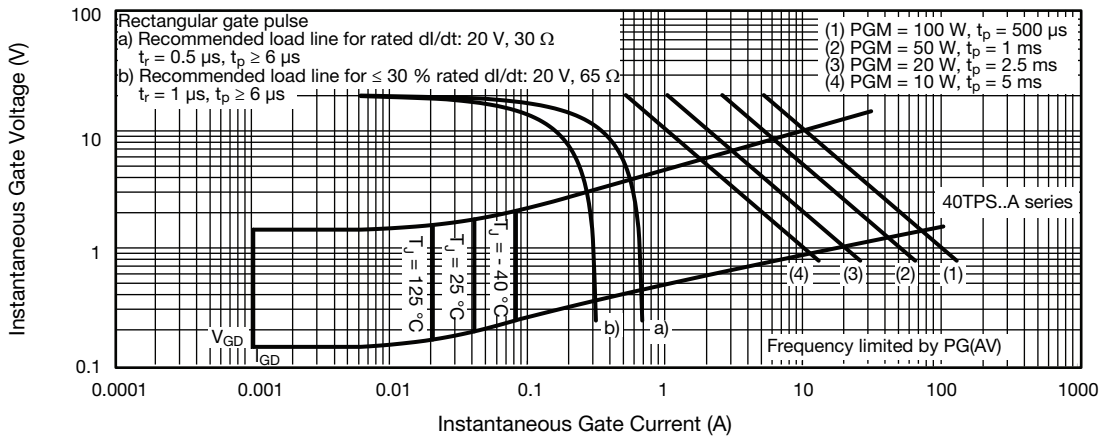


Fig. 9 - Gate Characteristics

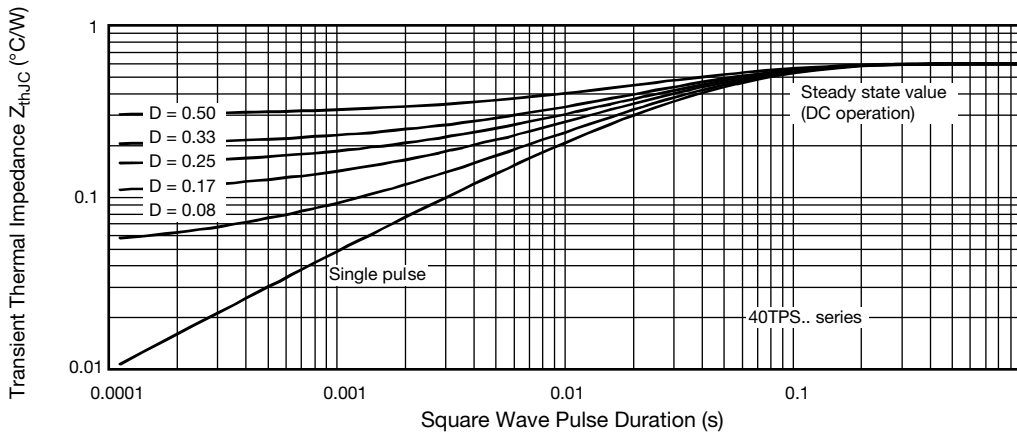
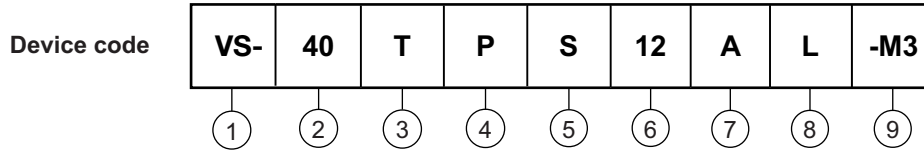


Fig. 10 - Thermal Impedance  $Z_{thJC}$  Characteristics



## ORDERING INFORMATION TABLE



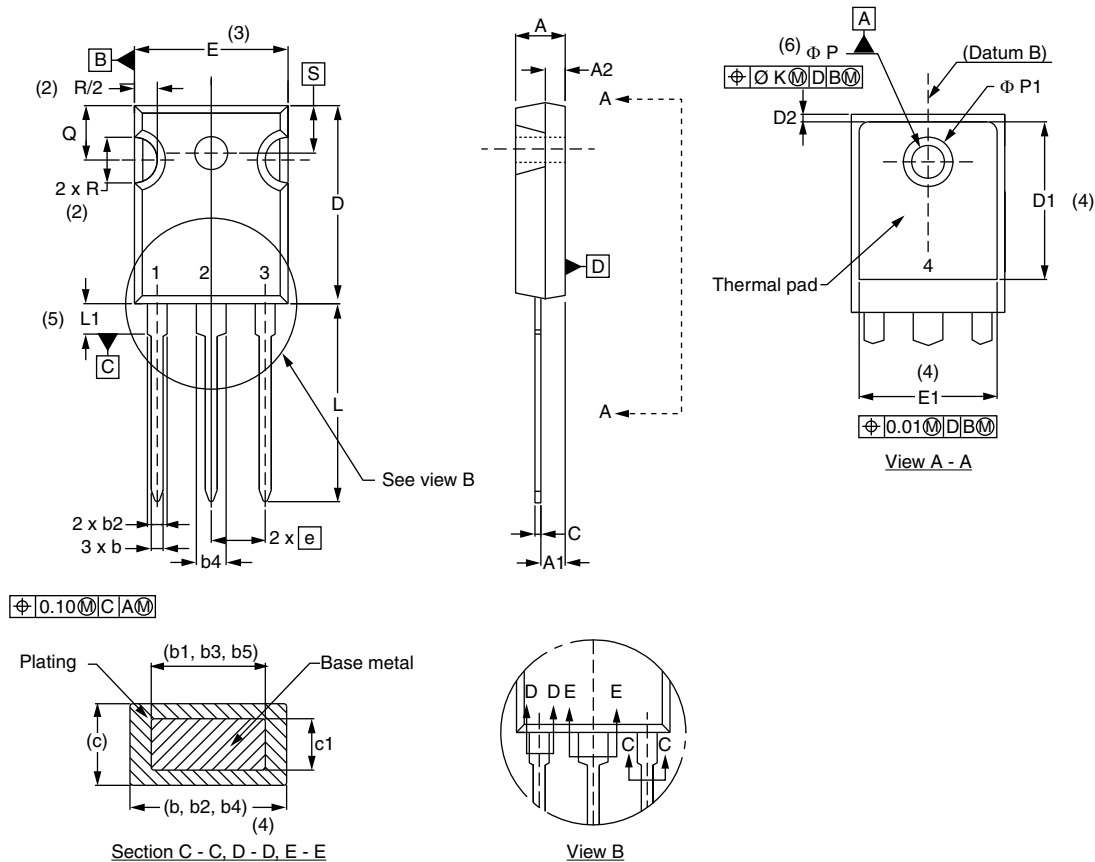
- 1** - Vishay Semiconductors product
- 2** - Current rating (40 = 40 A)
- 3** - Circuit configuration:  
T = thyristor
- 4** - Package:  
P = TO-247
- 5** - Type of silicon:  
S = standard recovery rectifier
- 6** - Voltage ratings 12 = 1200 V
- 7** -
  - A = Low Igt selection 40 mA maximum
  - None = standard Igt selection
- 8** - L = long leads
- 9** - Environmental digit:  
-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-40TPS12AL-M3	25	500	Antistatic plastic tubes
VS-40TPS12L-M3	25	500	Antistatic plastic tubes

LINKS TO RELATED DOCUMENTS		
Dimensions	TO-247AD 3L	<a href="http://www.vishay.com/doc?95626">www.vishay.com/doc?95626</a>
Part marking information	TO-247AD 3L	<a href="http://www.vishay.com/doc?95007">www.vishay.com/doc?95007</a>

### TO-247AD 3L

**DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209		D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098		E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055		e	5.46 BSC		0.215 BSC		
b1	0.99	1.35	0.039	0.053		Ø K	0.254		0.010		
b2	1.65	2.39	0.065	0.094		L	19.81	20.32	0.780	0.800	
b3	1.65	2.34	0.065	0.092		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		Ø P	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133		Ø P1	-	6.98	-	0.275	
c	0.38	0.89	0.015	0.035		Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033		R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3	S	5.51 BSC		0.217 BSC		
D1	13.08	-	0.515	-	4						

**Notes**

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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